New Product

SE07PB thru SE07PJ

Vishay General Semiconductor

## **Surface Mount ESD Capability Rectifiers**



DO-220AA (SMP)

### FEATURES

- Very low profile typical height of 1.0 mm
- Ideal for automated placement
- Oxide planar chip junction
- Low forward voltage drop
- Typical I<sub>R</sub> less than 0.1  $\mu$ A
- ESD capability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

#### **TYPICAL APPLICATIONS**

General purpose, polarity protection, and rail-to-rail protection in both consumer and automotive applications.

#### **MECHANICAL DATA**

Case: DO-220AA (SMP) Epoxy meets UL 94V-0 flammability rating Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD22-B102

E3 suffix for consumer grade, meets JESD 201 class 1A whisker test

Polarity: Color band denotes the cathode end

<b>MAXIMUM RATINGS</b> ( $T_A = 25 \text{ °C}$ , unless otherwise noted)							
PARAMETER	SYMBOL	SE07PB	SE07PD	SE07PG	SE07PJ	UNIT	
Device marking code		07B	07D	07G	07J		
Maximum repetitive peak reverse voltage	V <sub>RRM</sub>	100	200	400	600	V	
Average forward current (Fig. 1)	I <sub>F(AV)</sub>	0.7				А	
Peak forward surge current 10 ms single half sine-wave superimposed on rated load	I <sub>FSM</sub>	20				А	
Operating junction and storage temperature range	T <sub>J</sub> , T <sub>STG</sub>	- 55 to + 175				°C	

<b>ELECTRICAL CHARACTERISTICS</b> ( $T_A = 25 \text{ °C}$ , unless otherwise noted)							
PARAMETER	TEST CO	ONDITIONS	SYMBOL	TYP.	MAX.	UNIT	
Maximum instantaneous forward voltage $^{(1)}$	I <sub>F</sub> = 0.7 A I <sub>F</sub> = 0.7 A	T <sub>J</sub> = 25 °C T <sub>J</sub> = 125 °C	V <sub>F</sub>	0.965 0.865	1.05 0.95	v	
Maximum reverse current <sup>(2)</sup>	rated V <sub>R</sub>	T <sub>J</sub> = 25 °C T <sub>J</sub> = 125 °C	I <sub>R</sub>	- 3.7	5.0 50	μΑ	
Typical junction capacitance time	4.0 V, 1 MHz		CJ	5.0	-	pF	

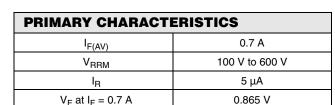
#### Notes:

(1) Pulse test: 300  $\mu s$  pulse width, 1 % duty cycle (2) Pulse test: Pulse width  $\leq$  40 ms



RoHS

COMPLIANT



175 °C

T<sub>.1</sub> max.



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<b>THERMAL CHARACTERISTICS</b> ( $T_A = 25 \degree C$ , unless otherwise noted)							
PARAMETER SYMBOL SE07PB SE07PD SE07PG SE07PJ				SE07PJ	UNIT		
Typical thermal resistance <sup>(1)</sup>	${f R}_{ heta JA} \ {f R}_{ heta JL} \ {f R}_{ heta JL}$	105 25 30		°C/W			

Note:

(1) Thermal resistance from junction to ambient and junction to lead mounted on P.C.B. with 5.0 x 5.0 mm copper pad areas.  $R_{\theta JL}$  is measured at the terminal of cathode band.  $R_{\theta JC}$  is measured at the top center of the body

### **IMMUNITY TO ELECTRICAL STATIC DISCHARGE TO THE FOLLOWING STANDARDS** $(T_{r} = 25 \degree C)$ unless otherwise noted)

(1 <sub>A</sub> = 25°C, unless otherwise hoted)						
STANDARD	TEST TYPE	TEST CONDITIONS	SYMBOL	CLASS	VALUE	
AEC Q101-001	Human body model (contact mode)	C = 100 pF, R = 1.5 k $\Omega$		НЗВ	> 8 kV	
AEC Q101-002	Machine model (contact mode)	C = 200 pF, R = 0 $\Omega$		M4	> 400 V	
JESD22-A114	Human body model (contact mode)	C = 150 pF, R = 1.5 k $\Omega$	V	3B	> 8 kV	
JESD22-A115	Machine model (contact mode)	C = 200 pF, R = 0 $\Omega$	V <sub>C</sub>	С	> 400 V	
IEC-61000-4-2 <sup>(2)</sup>	Human body model (contact mode)	C = 150 pF, R = 150 $\Omega$		4	> 8 kV	
IEC-61000-4-2	Human body model (air-discharge mode) <sup>(1)</sup>	C = 150 pF, R = 150 $\Omega$		4	> 15 kV	

Notes:

(1) Immunity to IEC-61000-4-2 air discharge mode has a typical performance > 30 kV

(2) System ESD standard

ORDERING INFORMATION (Example)							
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE			
SE07PJ-E3/84A	0.024	84A	3000	7" diameter plastic tape and reel			
SE07PJ-E3/85A	0.024	85A	10 000	13" diameter plastic tape and reel			

### **RATINGS AND CHARACTERISTICS CURVES**

(T<sub>A</sub> = 25 °C unless otherwise noted)

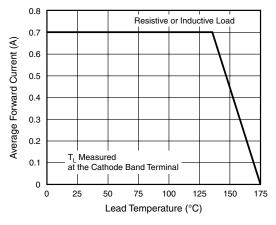


Figure 1. Maximum Forward Current Derating Curve

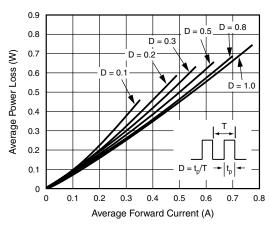


Figure 2. Forward Power Loss Characteristics



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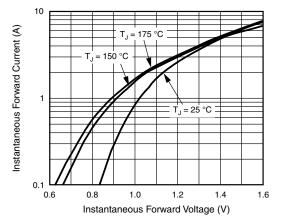


Figure 3. Typical Instantaneous Forward Characteristics

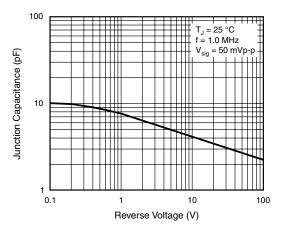


Figure 5. Typical Junction Capacitance

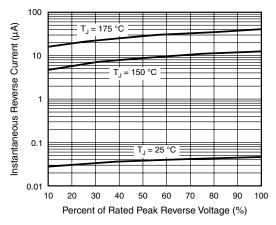
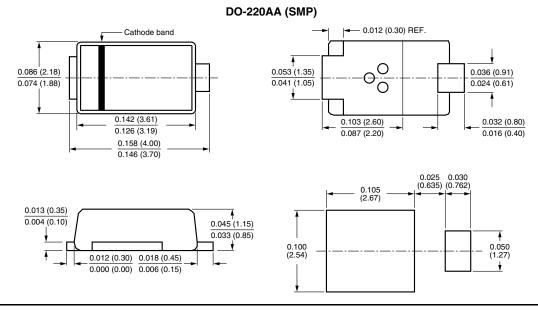


Figure 4. Typical Reverse Leakage Characteristics

#### **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)



For technical questions within your region, please contact one of the following: PDD-Americas@vishay.com, PDD-Asia@vishay.com, PDD-Europe@vishay.com



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